NSN 5962-01-093-8823

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View Online at https://aerobasegroup.com/nsn/5962-01-093-8823

Body Length:

1.060 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

Between 0.130 inches and 0.185 inches

Maximum Power Dissipation Rating:

275.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and 3-state output and low power

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Design Function And Quantity:

8 buffer, inverting

Case Outline Source And Designator:

D-8 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

18.00 nanoseconds propagation delay time, low to high level output and 23.00 nanoseconds propagation delay time, high to low level output

Special Features:

Nuclear hardness critical items

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

20 printed circuit

Specification Data:

813/0-mil-m-38510/32//usaf/ government specification

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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